



DEVELOPMENT OF DIELECTRIC-BASED HIGH GRADIENT ACCELERATING STRUCTURES

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AAC2006





OUTLINE

- 1. The Recent High Power rf Testing of Quartz Based DLA Structure
- 2. Ways to Higher Gradient for DLA Structures
 - > small I.D. quartz DLA structure design: Test high gradient and multipactor power scaling
 - ➤ Gapless DLA structure based on the new coupler design
 - ➤ Low loss double layer DLA structure





Part I

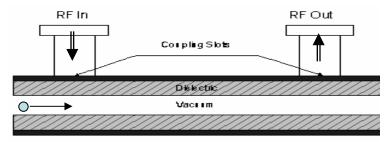
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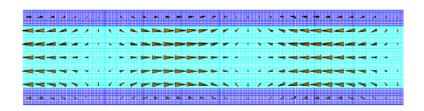




High Power RF Testing of The Quartz Based DLA Structure (I) -----Introduction

•Dielectric-Loaded Accelerating (DLA) structure is a potentially candidate for the high gradient accelerator in the future.





- •DLA Structure Development:
 - ·1) Coupler Breakdown (cured)
 - •2) Multipactor (Anomalous Power Absorption)
 - ·3) Joint Breakdown at the dielectric gap.
 - ·4) Tested Materials: MgCaTiO, Alumina, TiN coated Alumina
- •Motivation for Quartz Test: to test the multipactor effect of the different material due to quartz has relatively low secondary electron yield.

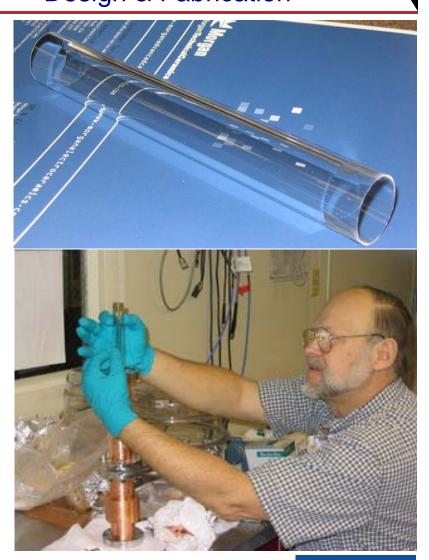




High Power RF Testing of The Quartz Based DLA Structure (II) ------Design & Fabrication

Parameters	Value
Material	Fused Silicon
Inner Radius	8.97mm
Outer Radius	12.08mm
Dielectric Const	3.78
Group Velocity	0.38c
R/Q	3.614kΩ/m
Shunt Impedance	27.9 MΩ/m *
Q	7715*
Power ATTN	0.35dB/m*
RF power needed to	
support 1MV/m	439kW
gradient	

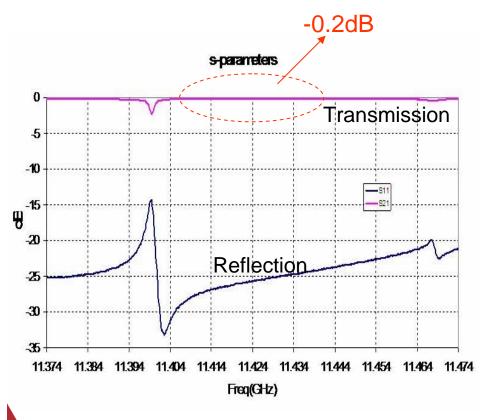
^{*}Loss tangent of the dielectrics is $2*10^{-5}$.

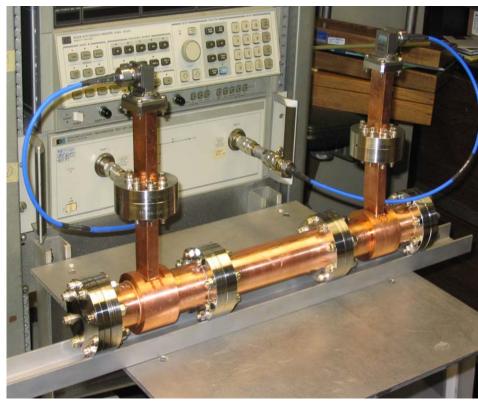






High Power RF Testing of The Quartz Based DLA Structure (III) ------Bench Testing

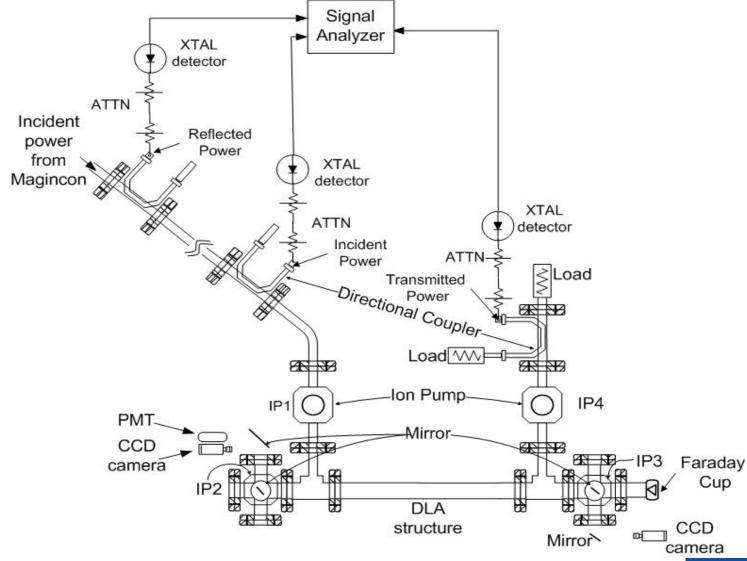








High Power RF Testing of The Quartz Based DLA -----High Power Testing Setup at NRL

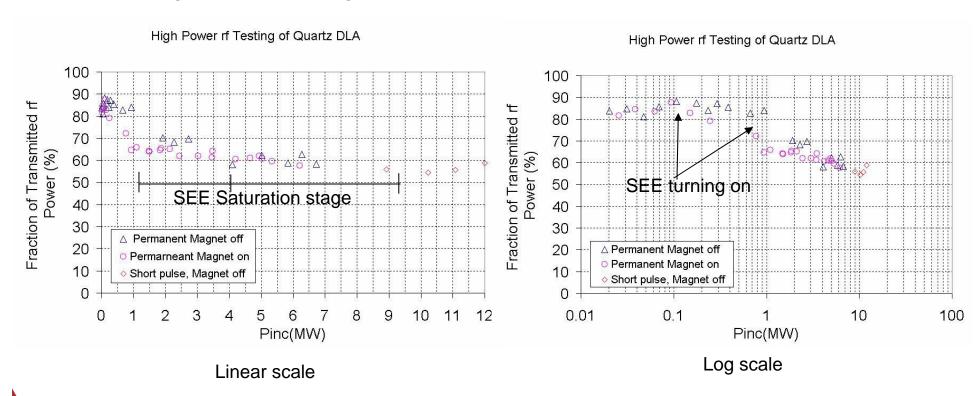






High Power RF Testing of The Quartz Based DLA Structure (V) ----- Testing Results (i)

No breakdown up to ~5 MV/m Large multipactor again





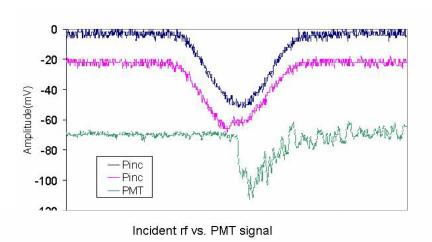


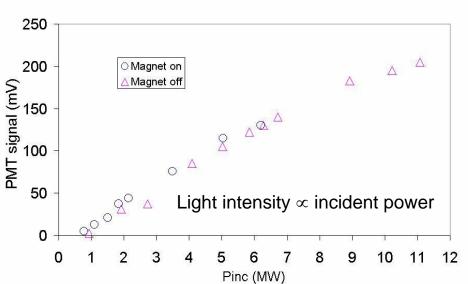


High Power RF Testing of The Quartz Based DLA Structure (VI)

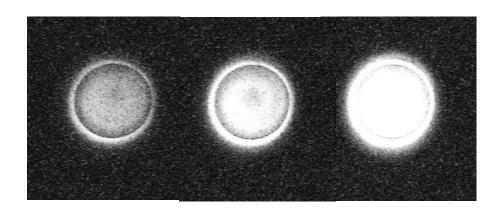
----- Testing Results (ii)

Using PMT to monitor Multipactor turning on







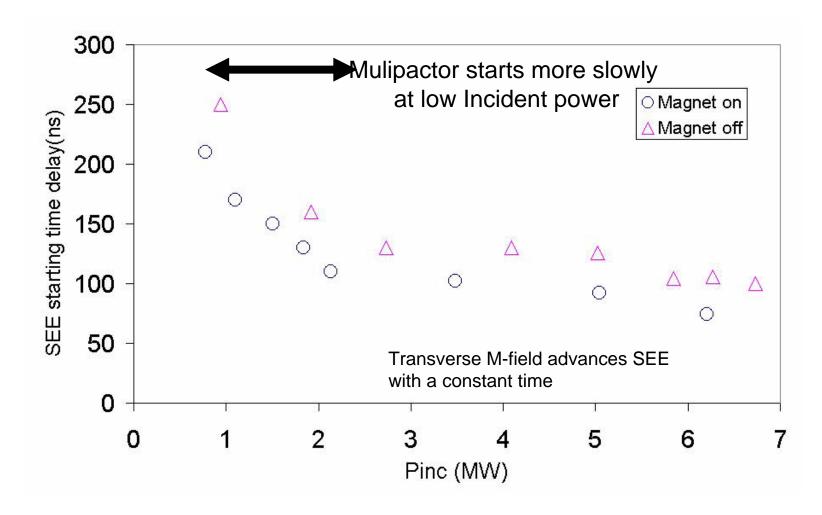








Multipactor Turn-on time



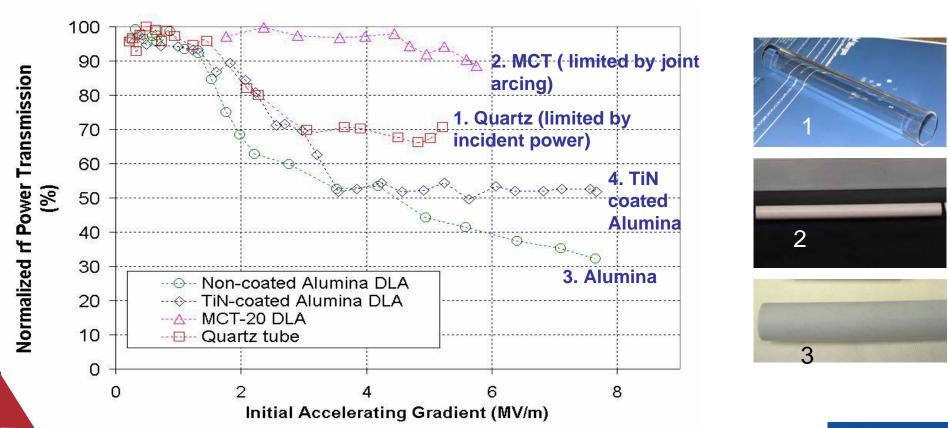




High Power RF Testing of The Quartz Based DLA Structure (VIII)

----- Comparison

- ➤ Dielectric Breakdown: Not seen in any structure
- ➤ Multipactor Induced Power Loss: lower in MCT and Quartz, saturate in Quartz and Al-TiN
- ➤ Joint Breakdown: >100 MV/m at joint in MCT;







High Power RF Testing of The Quartz Based DLA Structure (IX) ------ Summary

→DLA Progress to Date

- >Four generations of couplers and structures designed and tested.
- →Four different dielectric materials tested (Alumina, Fused Quartz, MCT, TiN coated Alumina)
- →No Breakdown of the bulk dielectric observed (up to 8 MV/m)
- Multipactoring and joint breakdown discovered; developed schemes to suppress
- → Gained fundamental understanding of the issues and developed new multipactoring theory.

→DLA Future High Power Tests

- → Joint-less DLA Structures (avoid joint breakdown)
- → Small I.D. (Reduce Multipactor)
- → Double Layer (Lower Power Attenuation)





Part II

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Small ID Quartz Based DLA structure design (I)

-----Parameters for different loaded materials

Loaded Material	dimensions	Group Velocity	Bandwidth (S11<-15dB)	Gradient per 10MW	Gradient per 100MW
Quartz $(\epsilon=3.75)$	ID=2mm OD=12.52mm	0.267c	480MHz	12.3MV/m	38.9MV/m
Cordierite (ε=4.76)	ID=2mm OD=10.85mm	0.21c	350MHz	14.6MV/m	46.2MV/m
Alumina (ε=9.77)	ID=3mm OD=8.23mm	0.1c	300MHz	19.8MV/m	62.6MV/m
MCT (ε=20)	ID=3mm OD=6.42mm	0.05c	42MHz	26.5MV/m	83.8MV/m





zie Small ID Quartz Based DLA structure design (II) 1977 1713 ----- simulation 1450 S-Parameter Magnitude in dB **6**59 45/T 4285 S-Parameter Magnitude in dB 3714 Highest field appears 3142 with the gap induced. 2571 2000 1428 -857 -286 -





Frequency / GHz

Part II

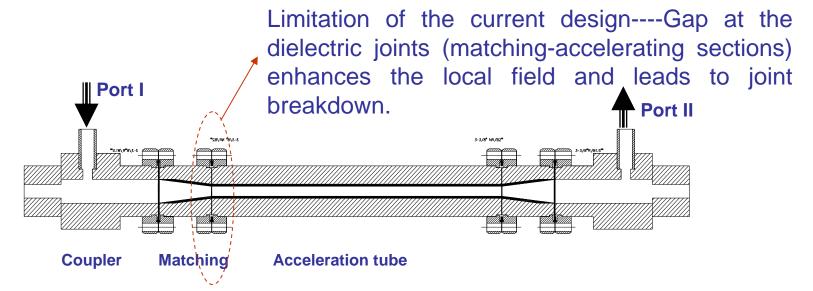
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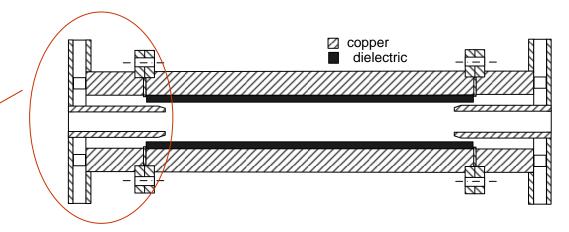


Gapless DLA structure based on the new coupler design*(I)

----- concept



New design uses the coaxial coupler which eliminates the dielectric taper section in the current design



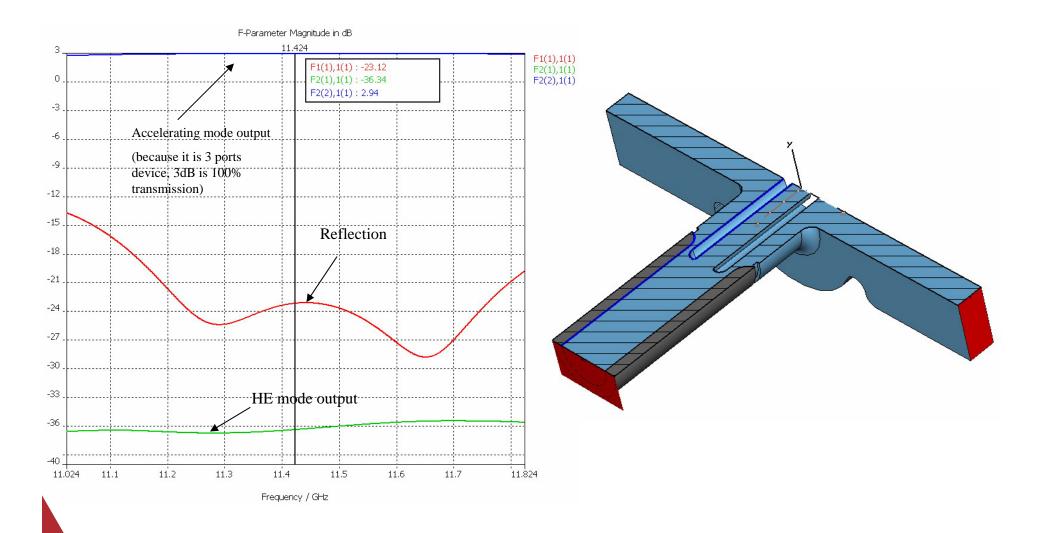






Gapless DLA structure based on the new coupler

design (II) ----- coupler simulation



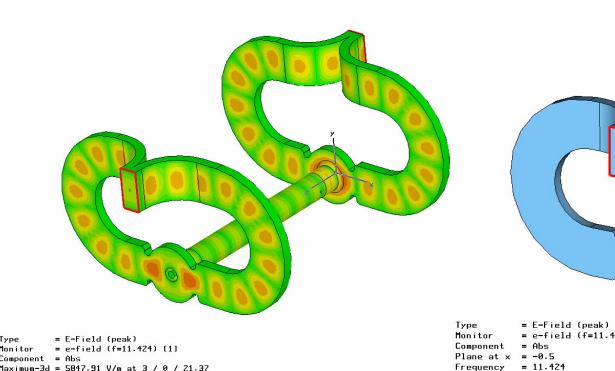




Gapless DLA structure based on the new coupler design (III) ----- Structure simulation

= 90 degrees

Maximum-2d = 5301.87 V/m at



Monitor Component = Abs

Maximum-3d = 5847.91 V/m at 3 / 0 / 21.37

Frequency = 11.424 = 0 degrees

There is no dielectric gap in the structure.

·Highest E-field appears at inner conductor tip, but the field enhancement ratio has only 1.6 to the accelerating gradient.





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Part II

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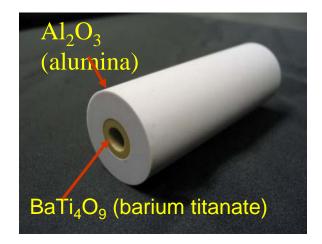
Low loss double layer DLA structure (I)

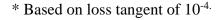
----- Concept

X-band Dual layer Dielectric-Loaded Accelerating Structure, funded by SBIR, is being developed at Euclid Techlabs, LLC in recent several months. So far, the entire targets proposed in Phase I plan have been accomplished which include fabrication of dual layer ceramic tube, simulation and fabrication of TM₀₃ mode launcher and bench testing.

Ceramic with high permittivity (37) Ceramic with low permittivity (9.7)	☐ Air ☑ Metal jacket	Group velocity (×c)	R (MΩ/m)	R/Q (Ω/m)	Power Attn (dB/m)
	1 layer DLA TM ₀₁ mode IR:3—4.13mm	3%	11.7*	1681*	-20*
	1 layer DLA TM ₀₃ mode IR:3—8.49mm	3%	7.4*	1553*	-7.8*
	2-layer DLA TM ₀₃ Mode 5.17—12.02mm	6%	14.5*	2040*	-2.3*





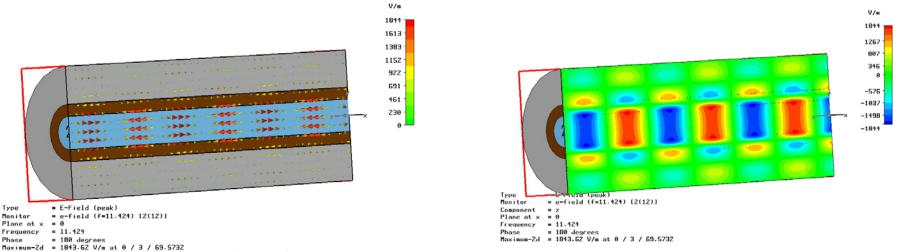




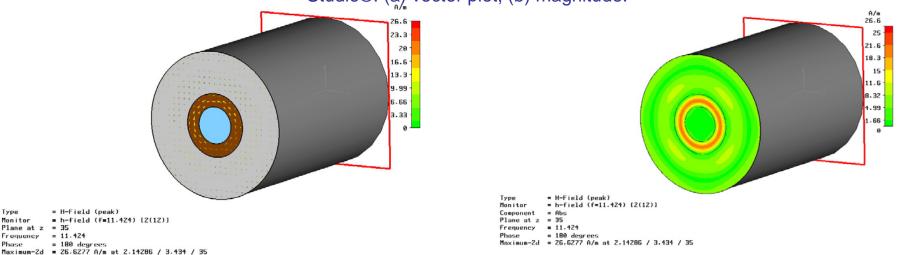


Low loss double layer DLA structure (II)





Electric field of dual layer DLA structure simulated with Microwave Studio®: (a) vector plot; (b) magnitude.



Magnetic field pattern of the double layer DLA structure simulated with Microwave Studio®: (a) vector plot; (b) magnitude.



Monitor

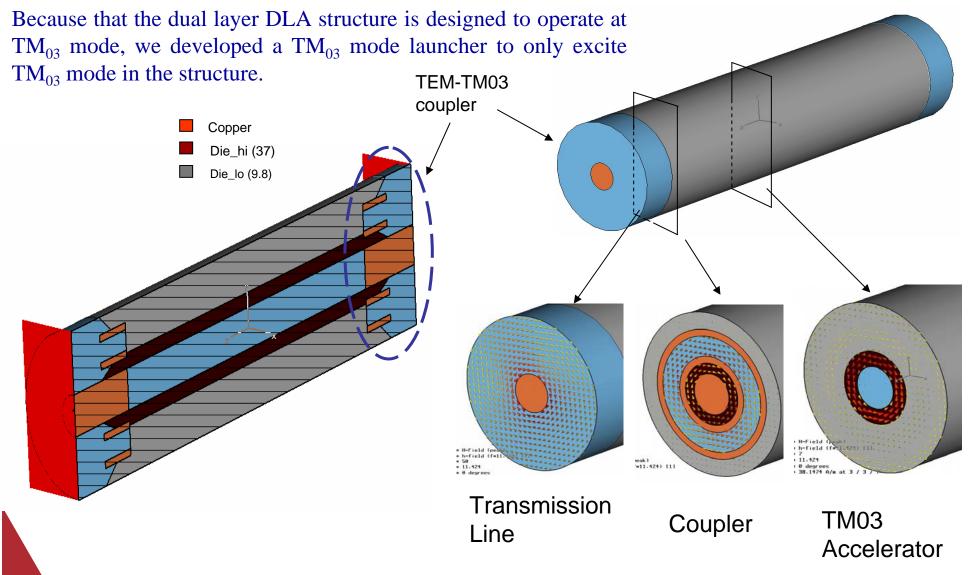
Plane at z = 35Frequency = 11.424



= H-Field (peak)



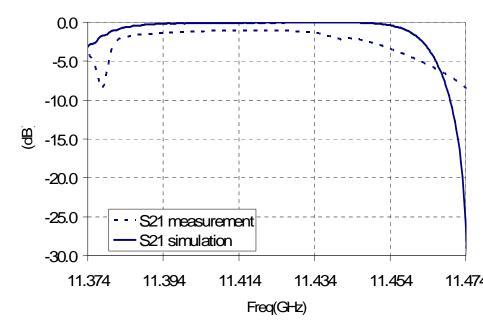
Low loss double layer DLA structure (III) ____TM₀₃ Mode Launcher



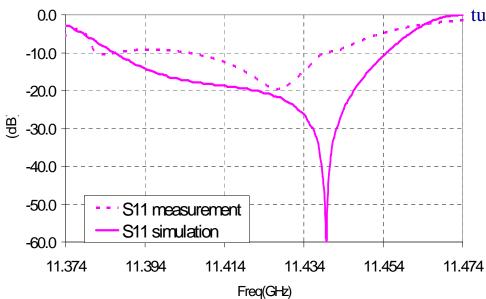




Low loss double layer DLA structure (IV) Bench Testing



Based on the results of bench testing, the dual layer DLA structure has 4dB/m attenuation. which slightly larger than the theoretical value, 2.5dB/m. It is partly due to the larger loss from copper rough surface, and 11.474 slightly higher loss tangent of ceramc tube.





Summary

- We have tested RF and multipactor behaviors of the quartz based DLA structure;12MW rf power was input without breakdown; saturation stage of the multipactor appeared at 1MW rf input; the same structure will be tested with higher rf power.
- We are moving forward with some new DLA structures design to try to achieve a higher accelerating gradient and lower RF loss.



